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NASA TECHNICAL MEMORANDUM

NASA TM-78194

THE MSFC SILICON GATE SILICON-ON-SAPPHIRE STANDARD CELL LIBRARY

By Design Techniques Branch Electronics Development Division Electronics and Control Laboratory

September 1978



George C. Marshall Space Flight Center Marshall Space Flight Center, Alabama



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THE MSFC SILICON GATE SILICON ON SAPPHIRE STANDARD CELL LIBRARY (with wire bond)

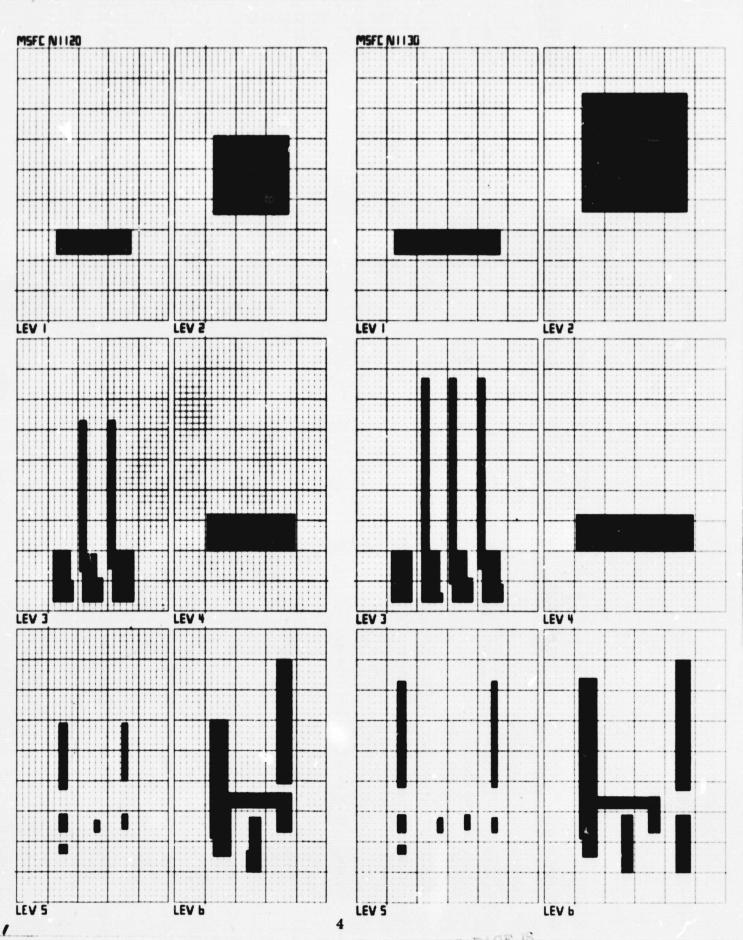
This is a pictorial representation of the MSFC silicon gate, silicon on sapphire standard cell library (for wire bond) revision B dated July 22, 1974. The cells are intended for use with the PR2D program. They were designed by RCA or MSFC as indicated in the cell listing below. Each major grid line represents 1 mil on the chip, minor grid lines represent 0.5, 0.2, or 0.1 mil. One major grid line pair extends beyond the frame, thus pinpointing the location of the cell reference point. Each cell is identified by the technology code "N" and its cell number. The level is indicated below each frame. If no geometry is required on a particular level, the level picture is not shown (dummy levels). Some cells require identical geometries on two or more levels. In this case the geometry is shown only once. The cell listing denotes such duplicate levels.

CELL LISTING

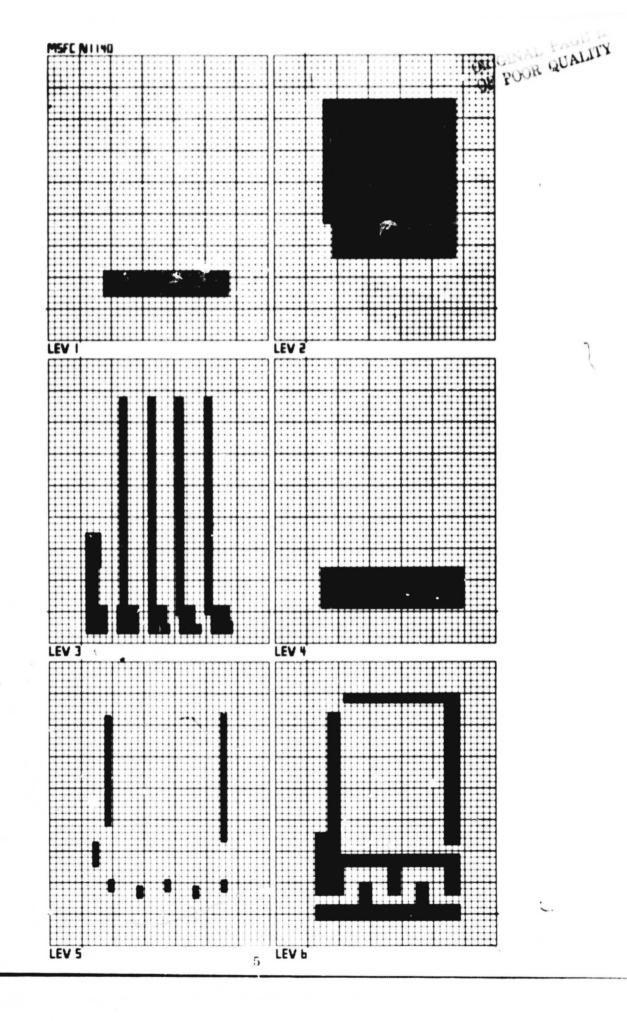
CELL#		DUMMY LEVEL(S)	DUPLICATE LEVEL(S)	SOURCE
1120	2 - Input NOR gate	1~	•	RCA
1130	- Input NOR	!~	•	RCA
1140	- Input NOR	. (~	•	RCA
1220	- Input NAN	. 1~	•	S. S.
1230	- Input NAND	. (~	•	RCA
1240	- Input NAND	1~	ı	RCA
1310	Inverter	۱~	ı	RCA
1330	$x = B \cdot A + \overline{B} \cdot C$	1-	ı	RCA
1340	$x = B \cdot A + \overline{B} \cdot C$	1~	•	RCA
1510	Non-Inverter Buffer	-	•	RCA
1520	Buffer Inverter	-	•	RCA
1620	2 - Input AND gate	7	•	RCA
1630	3 - Input AND gate	2	•	RCA
1640	- Input AND	2		RCA
1720	2 - Input CR gate	7	•	RCA
1890	3 x 2 - Input AND - 3 X NOR gate	2	ı	RCA
1910	$x = \overline{A \cdot B + B \cdot C + C \cdot D}$	1-	•	RCA
1920	$x = A \cdot B \cdot C$; $Y = B \cdot C$	2	ı	RCA
2310 2820	2 - Input exclusive OR gate D-Master - Slave flip flop		1 1	RCA

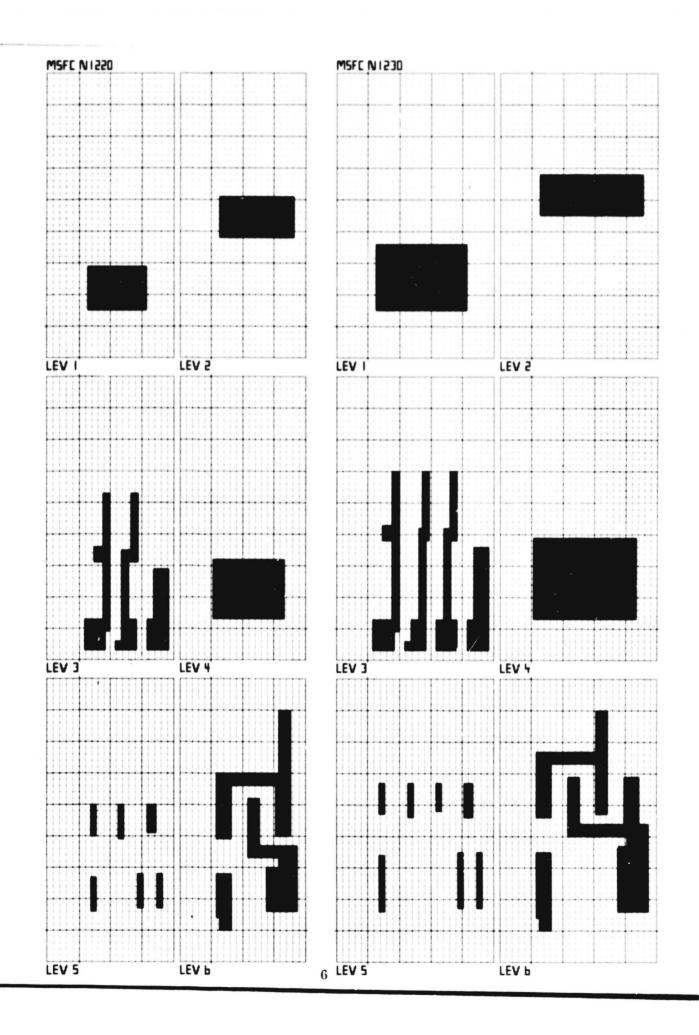
CELL LISTING (Continued)

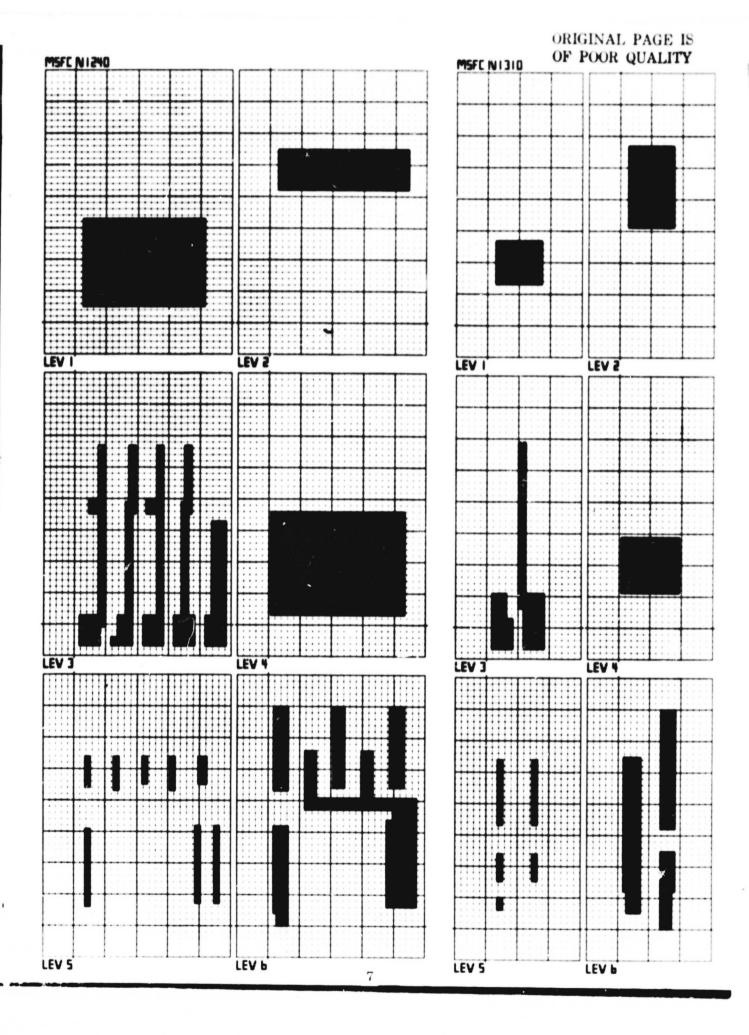
CELL #	FUNCTION	DUMMY LEVEL(S)	DUPLICATE LEVELS' SOMBCE	a) all OS
9010 9060 9070 9100 9110	Input Pad VDD Buffer Inverter Pad GND Buffer Inverter Pad Ground Pad VDD Pad	2 - 2,3,4,5 2,3,4,5	7=level 7 of cell 9010 7=level 7 of cell 9010 7=level 7 of cell 9010 7=level 7 of cell 9010	RCA RCA RCA RCA
9210 9220 9250 9260 9310 9320	On-chip alignment mark On-chip alignment mark Off-chip alignment mark Off-chip alignment mark P - Test Transistor N =Test Transistor	, ' , ' <u>'</u> , ' , ' , ' , ' , ' , ' , ' , ' , ' ,	2=4=5=7=lev.1;6=lev.3 2=4=5=7=lev.1;6=lev.3	RCA RCA RCA MSFC RCA RCA
9400 9410 9420 9430 9440 9450	Level Identification Identification "NASA N" Identification "MSFC N" (all levels) Identification "MSFC N" (lev. 6 only) Identification "N" (lev. 6 only) Identification "MSFC" (lev. 6 only)	- 1,2,3,4,5,7 1,2,3,4,5,7 1,2,3,4,5,7	2=3=4=5=6=7=1ev. 1 2=3=4=5=6=7=1ev. 1 6=1ev 1 of cell 9420	MSFC MSFC MSFC MSFC MSFC
9500 9700 To 9790	Feedthrough Numeric Characters 0-9 (all levels)	1,2,4,7	2=3=4=5=6=7=1ev. l	R CA R CA
9800 To 9890	Numeric Characters 0-9 (lev. 6 only)	1, 2, 3, 4, 5, 7	6=level 1 of Cell Group 9700/9790	MSFC

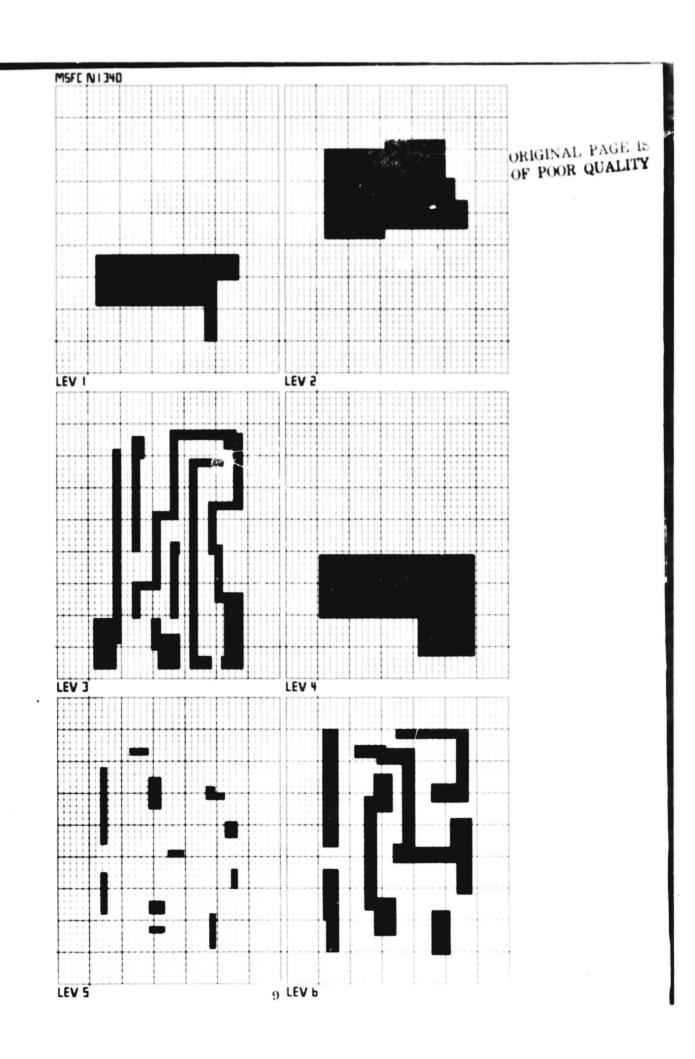


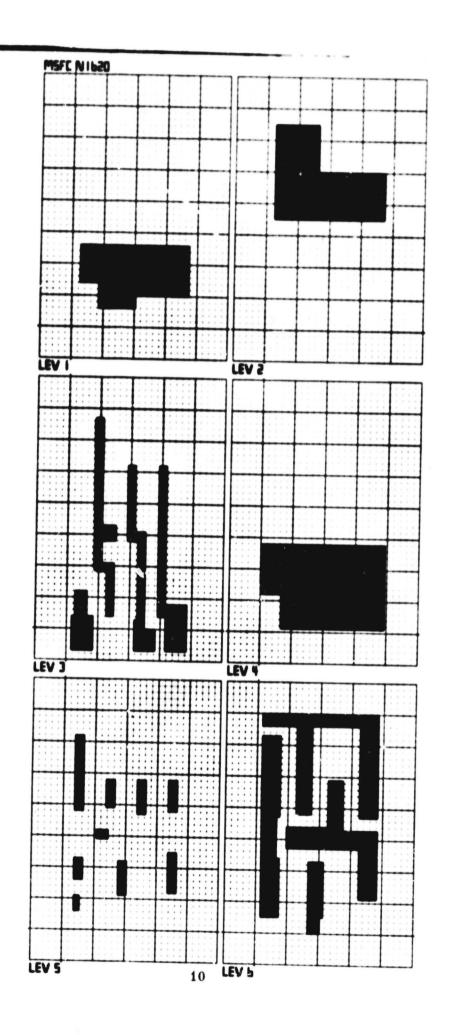
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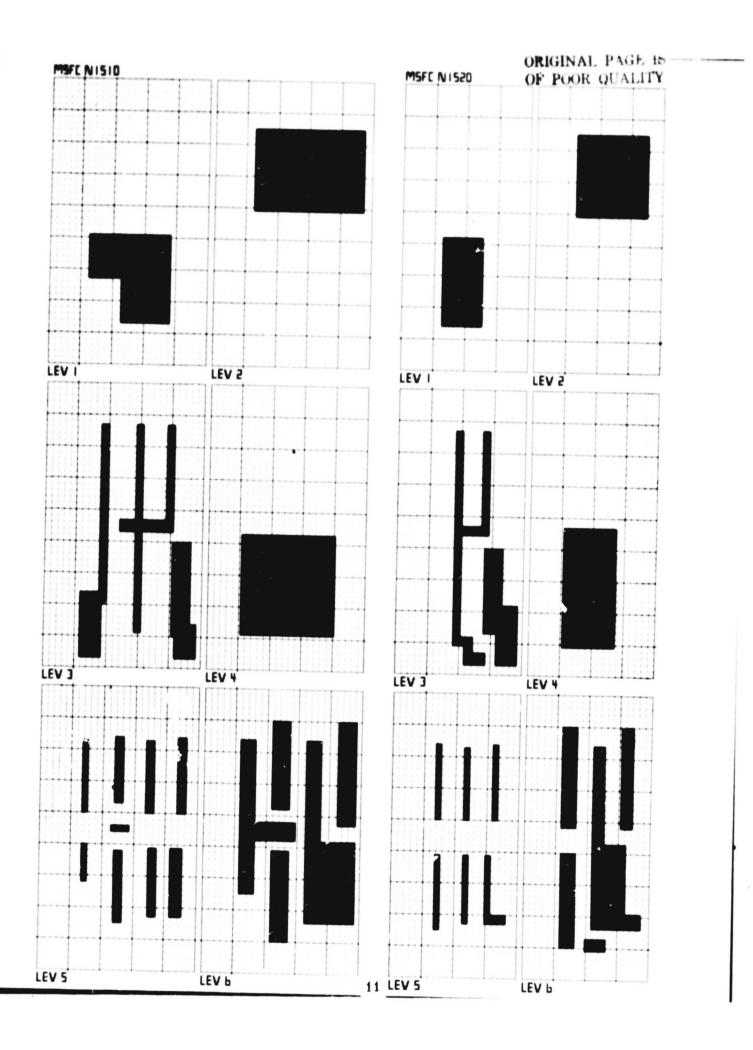


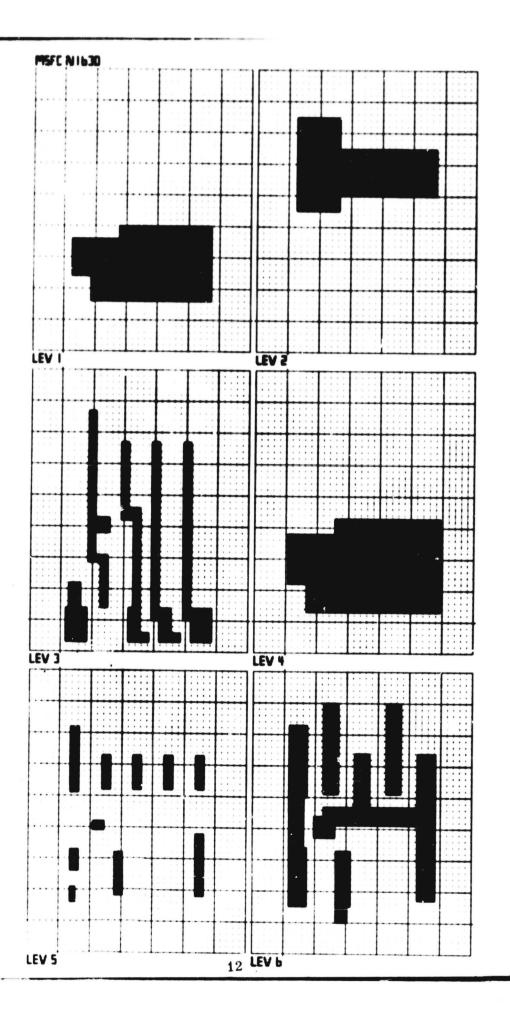


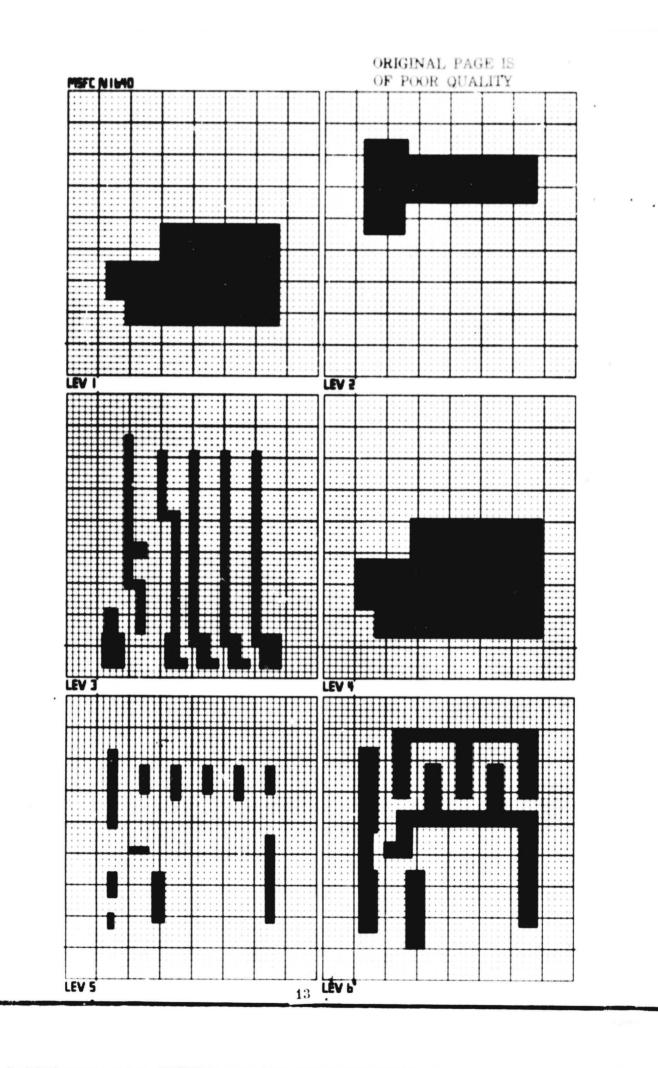


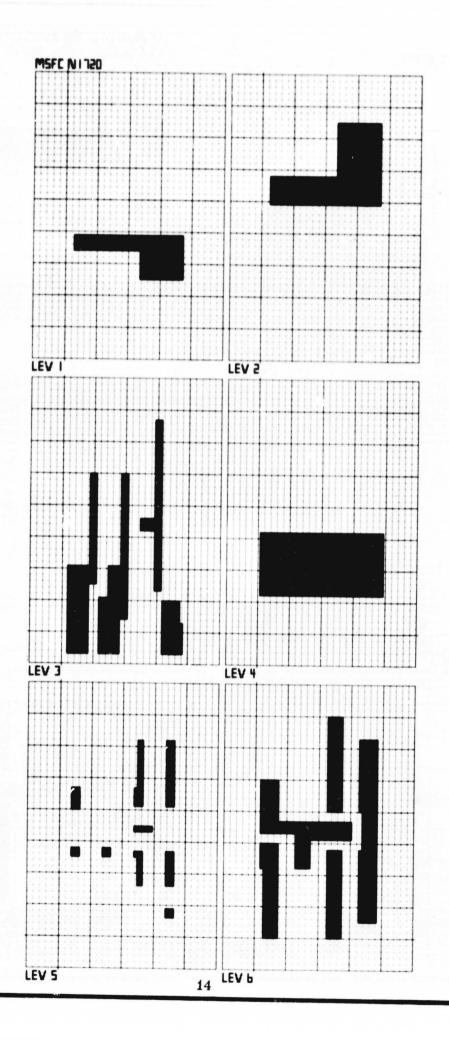






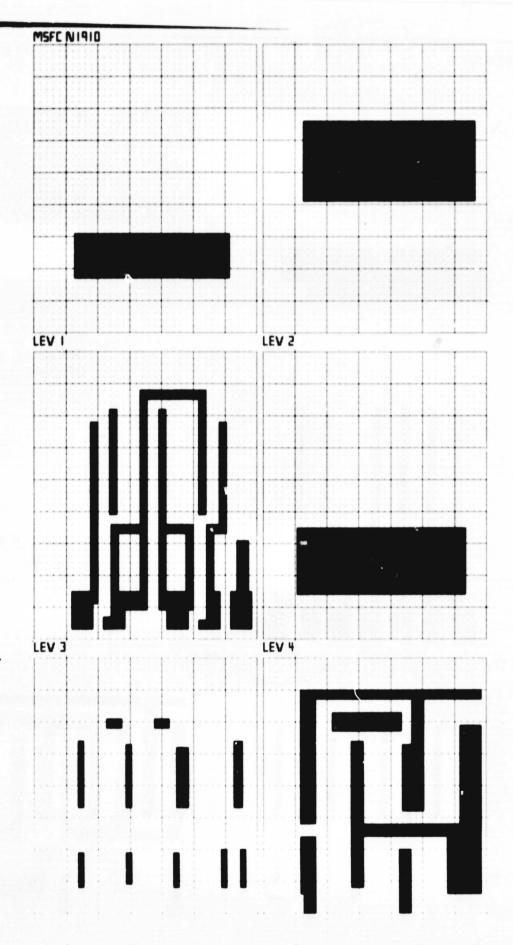


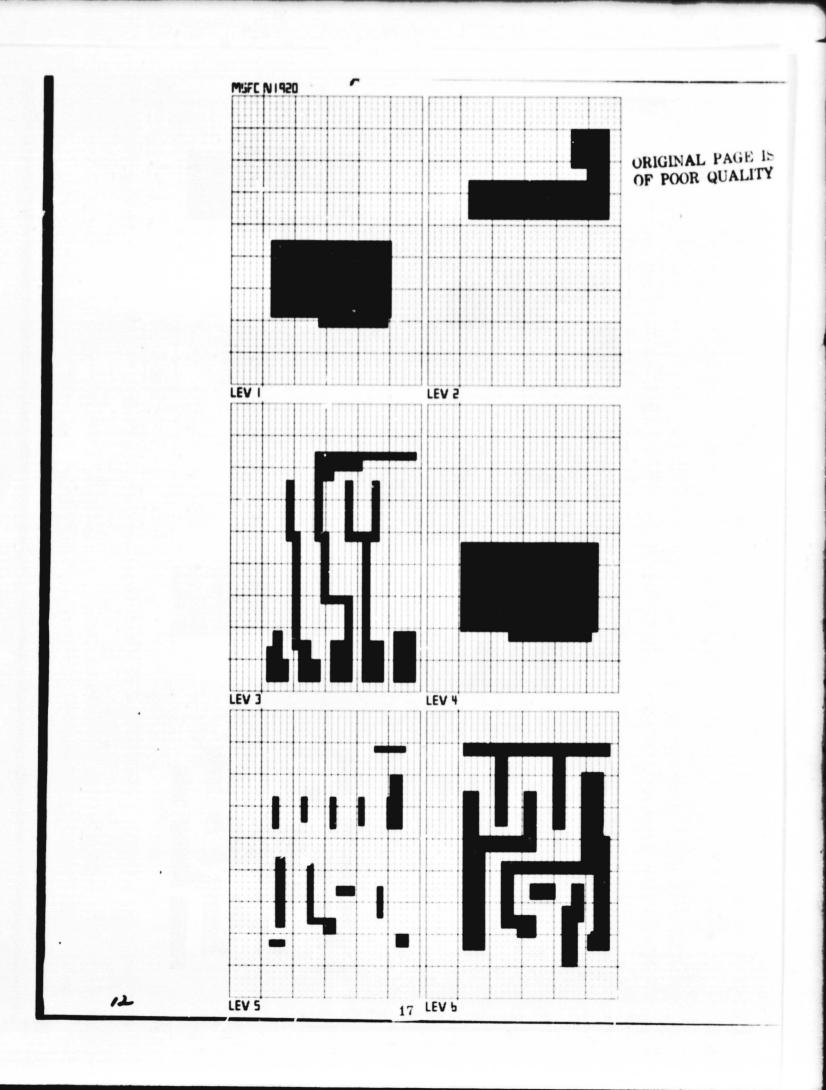


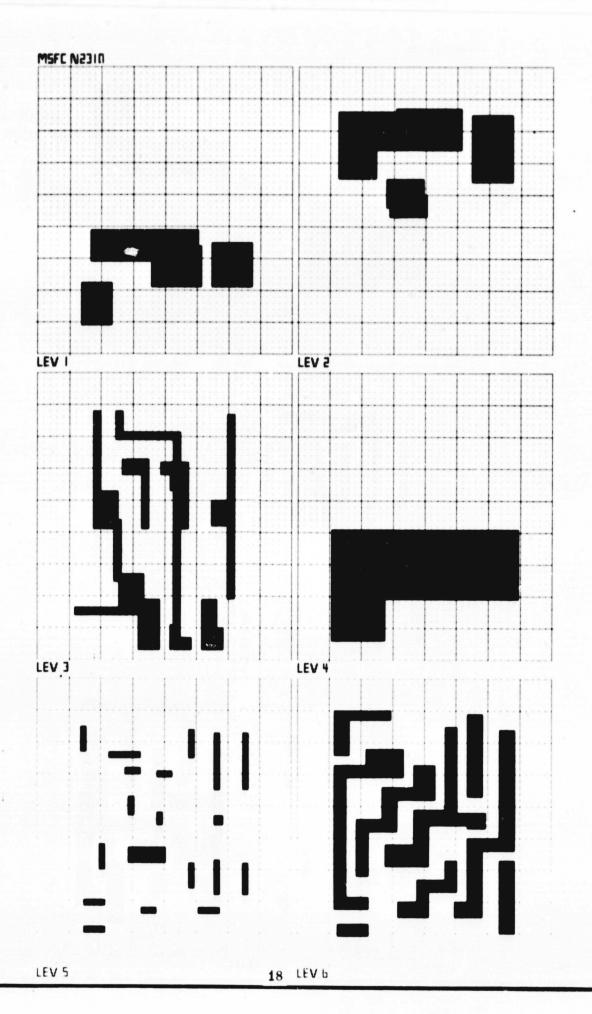


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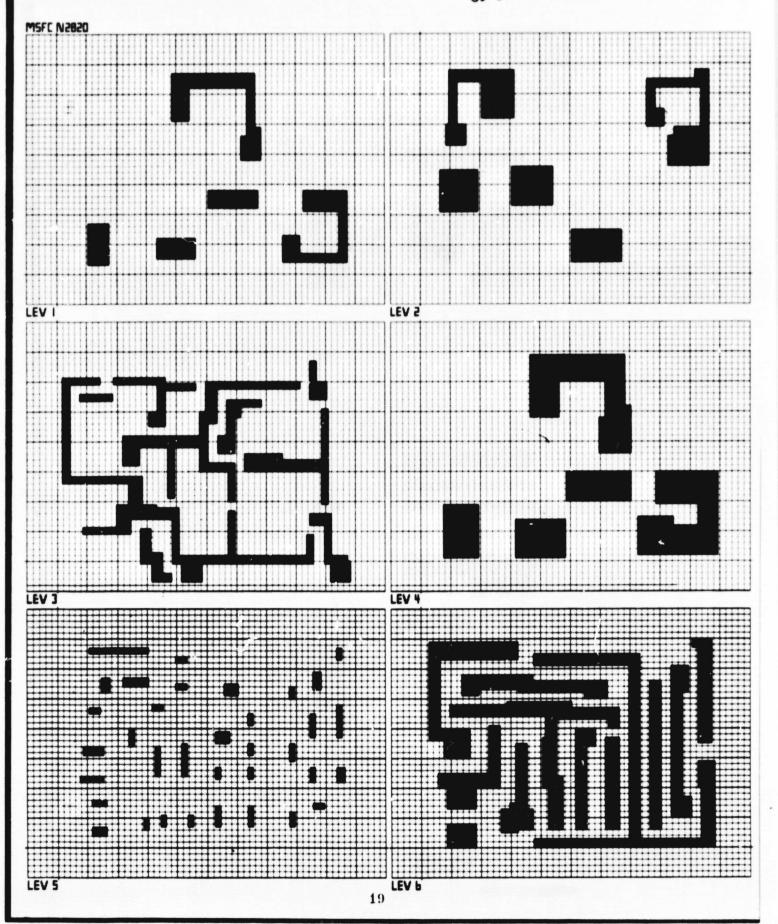
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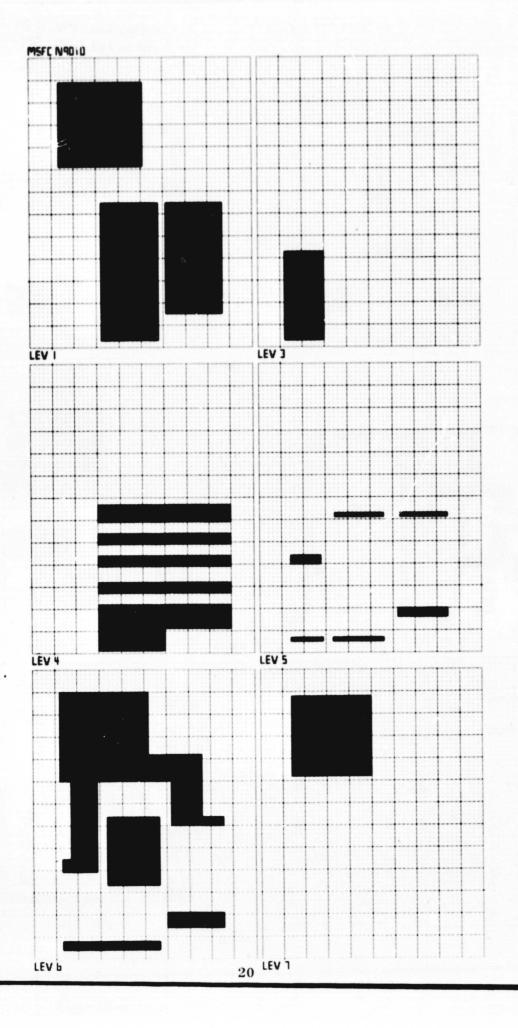


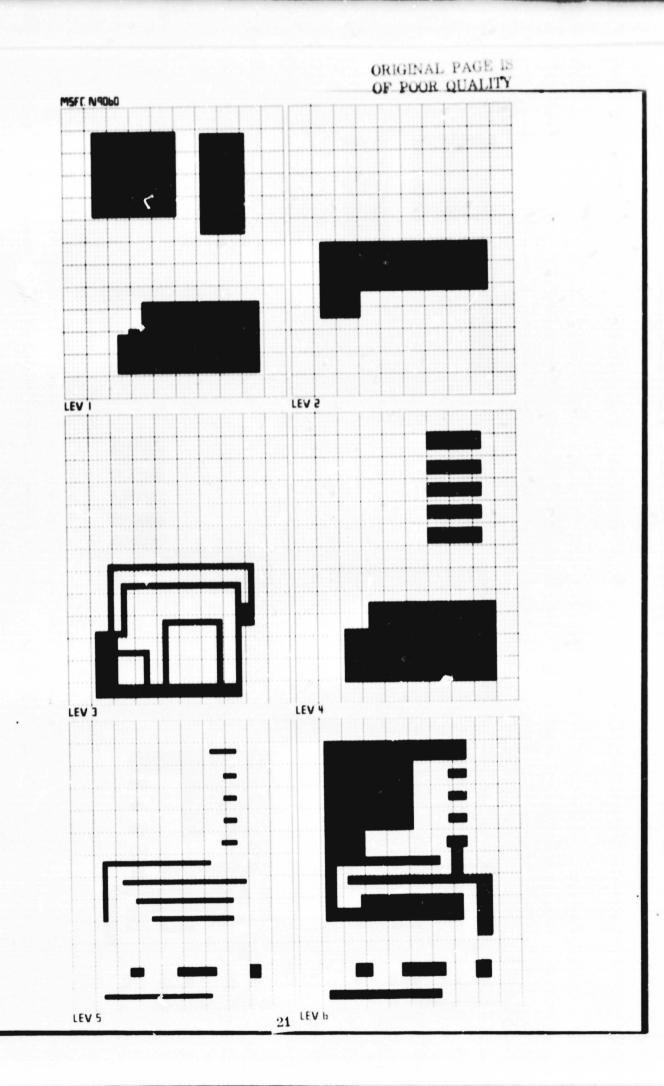


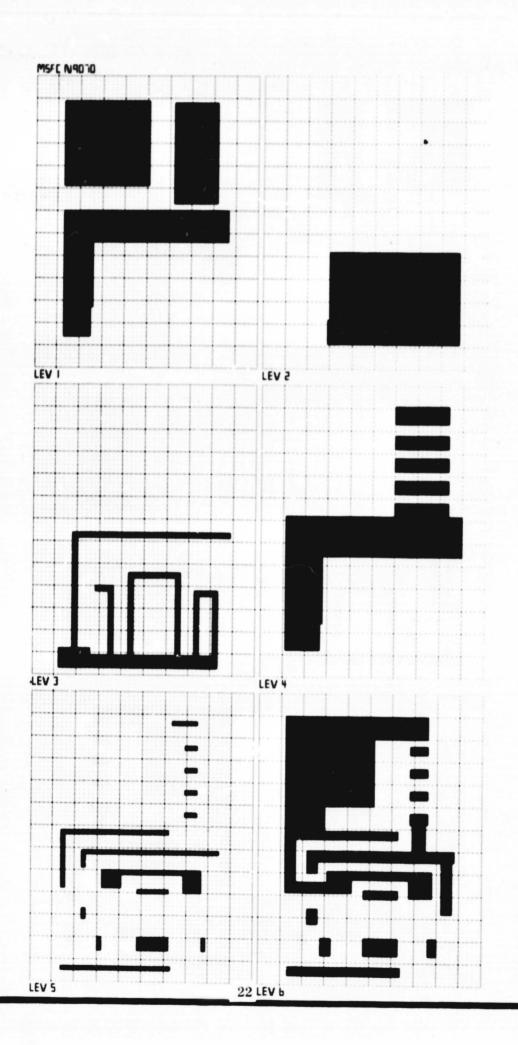


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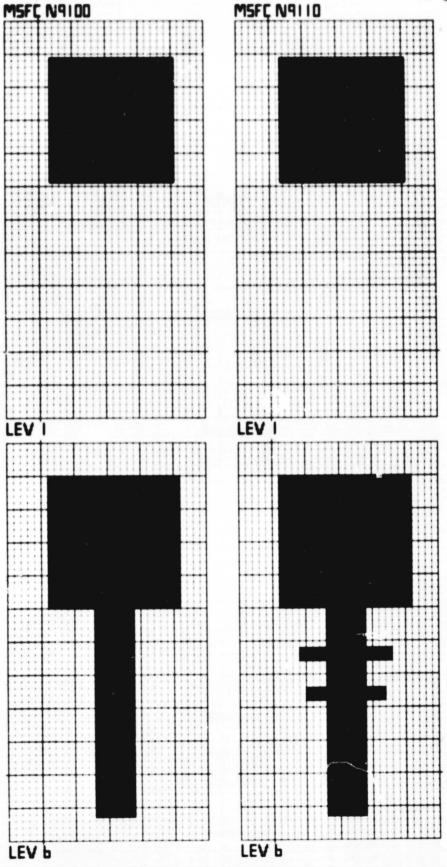


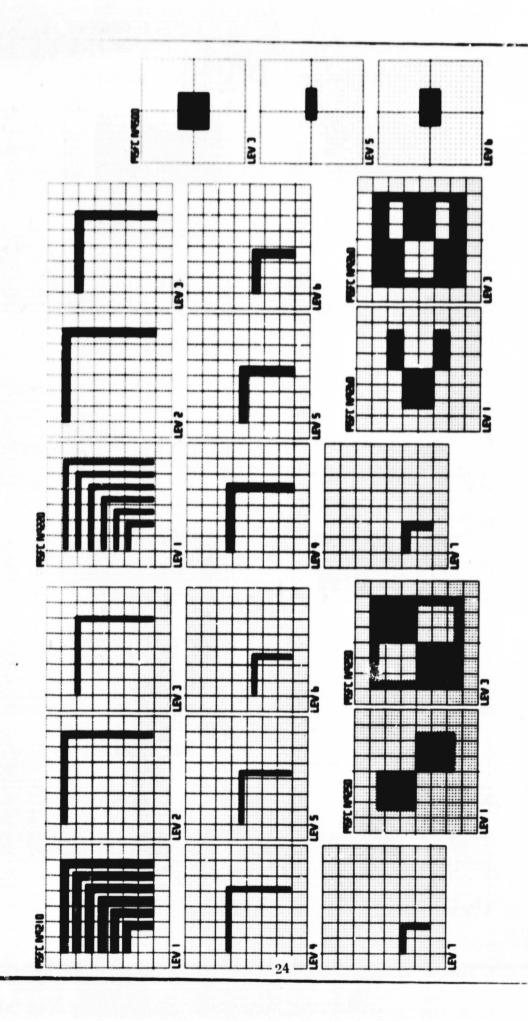


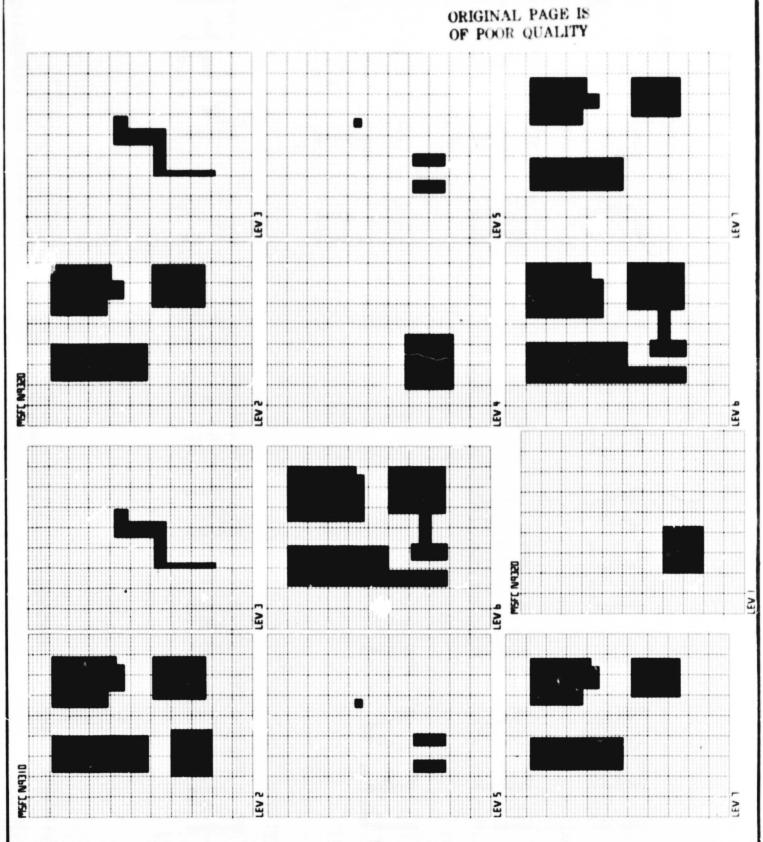


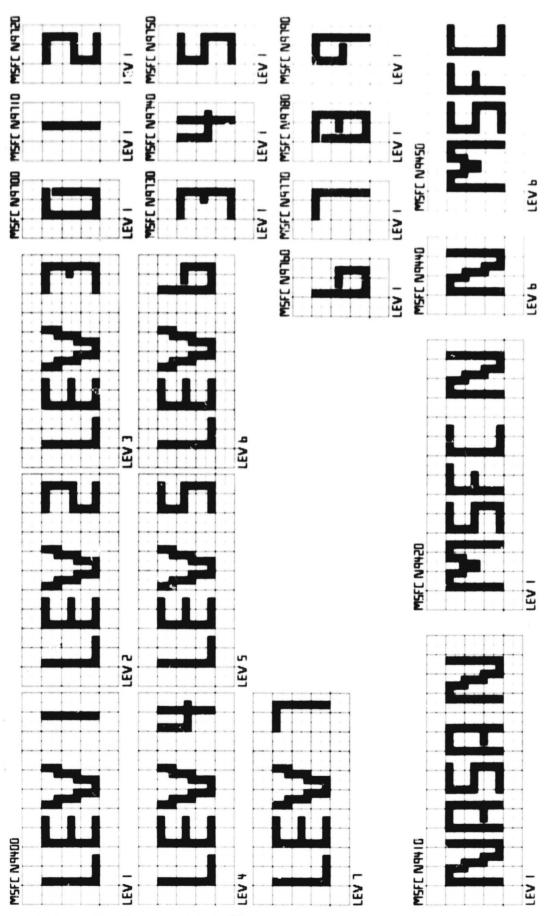


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